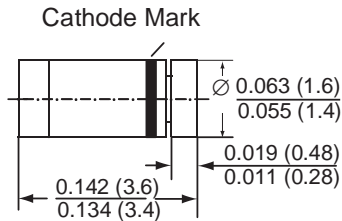


Voltage Stabilizers

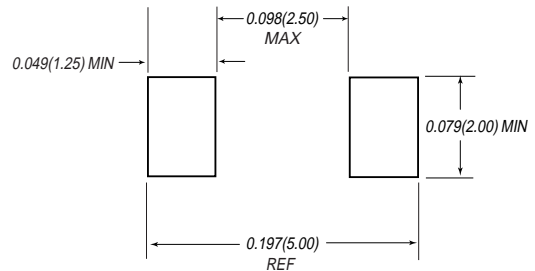


MiniMELF (SOD-80C)



Dimensions in inches and (millimeters)

Mounting Pad Layout



Mechanical Data

Case: MiniMELF Glass Case (SOD-80C)

Weight: approx. 0.05g

Cathode band color: Blue

Packaging codes/options:

D1/10K per 13" reel (8mm tape), 20K/box

D2/2.5K per 7" reel (8mm tape), 20K/box

Features

- Silicon Planar Stabilizer Diodes
- Monolithic integrated analog circuits in MiniMELF case, designed for small power stabilizer and limitation circuits, providing low dynamic resistance and high-quality stabilization performance as well as low noise. In the reverse direction, these devices show the behavior of forward-biased silicon diodes.
- The end of the device marked with the cathode ring is to be connected: LL1.5 and LL2 to the negative pole of the supply voltage; LL2.4 thru LL5.1 to the positive pole of the supply voltage
- These diodes are also available in DO-35 case with the type designation ZTE1.5 ... ZTE 5.1.

Maximum Ratings (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Operating Current (see Table "Characteristics")			
Inverse Current	I _F	100	mA
Power dissipation at T _{amb} = 25°C	P _{tot}	300 ⁽¹⁾	W
Junction temperature	T _J	150	°C
Storage temperature range	T _S	-55 to +150	°C

Electrical and Thermal Characteristics (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Forward Voltage at I _F = 10mA	V _F	-	-	1.1	V
Temperature Coefficient of the stabilized voltage at I _Z = 5mA	LL1.5, LL2	α _{VZ}	-	-26	10 ⁻⁴ /°C
	LL2.4, LL5.1	α _{VZ}	-	-34	10 ⁻⁴ /°C
Thermal resistance junction to ambient air	R _{θJA}	-	-	400 ⁽¹⁾	°C/W

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Type	Operating Voltage at I _Z = 5mA ⁽²⁾ V _Z (Ω)	Dynamic resistance at I _Z = 5mA r _{Zj} (Ω)	Permissible operating current at T _{amb} = 25°C ⁽¹⁾ I _Z max. (mA)
LL1.5	1.35 ... 1.55	13(<20)	120
LL2	2.0 ... 2.3	18(<30)	120
LL2.4	2.2 ... 2.56	14(<20)	120
LL2.7	2.5 ... 2.9	15(<20)	105
LL3	2.8 ... 3.2	15(<20)	95
LL3.3	3.1 ... 3.5	16(<20)	90
LL3.6	3.4 ... 3.8	16(<25)	80
LL3.9	3.7 ... 4.1	17(<25)	75
LL4.3	4.0 ... 4.6	17(<25)	65
LL4.7	4.4 ... 5.0	18(<25)	60
LL5.1	4.8 ... 5.4	18(<25)	55

Notes: (1) Valid provided that electrodes are kept at ambient temperature at a distance of 8mm from case

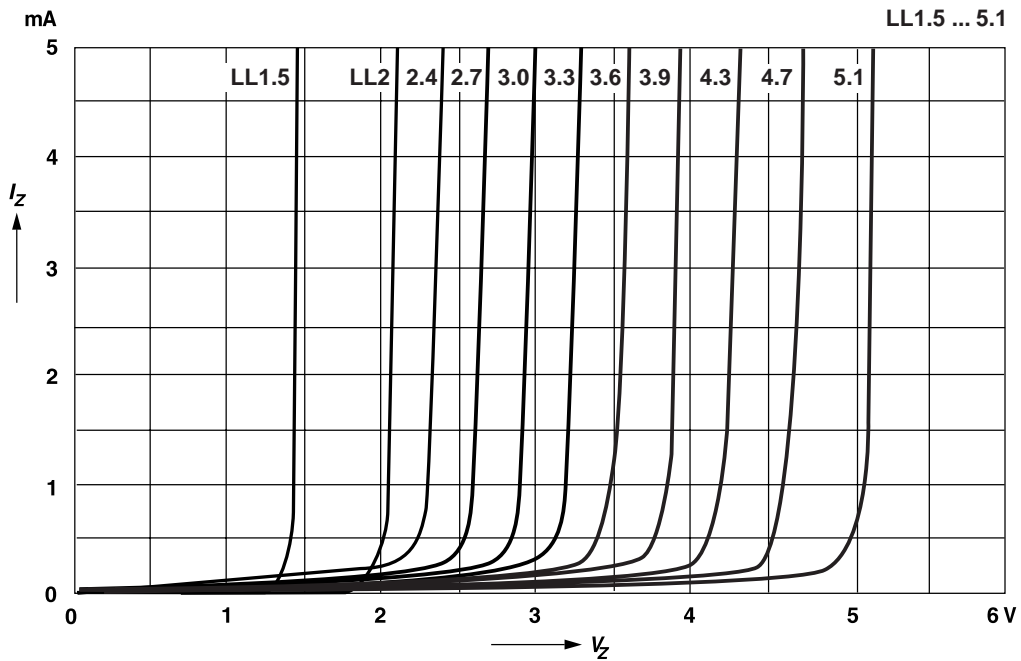
(2) Tested with pulses t_p = 5ms



Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

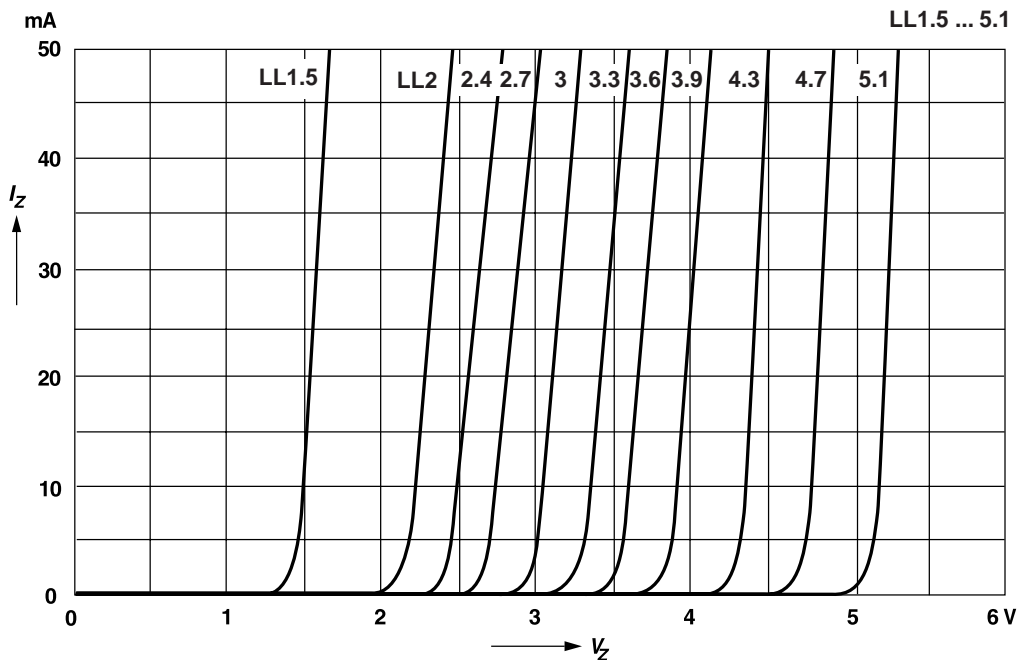
Breakdown characteristics

$T_j = \text{constant (pulsed)}$



Breakdown characteristics

$T_j = \text{constant (pulsed)}$



LL1.5 thru LL5.1

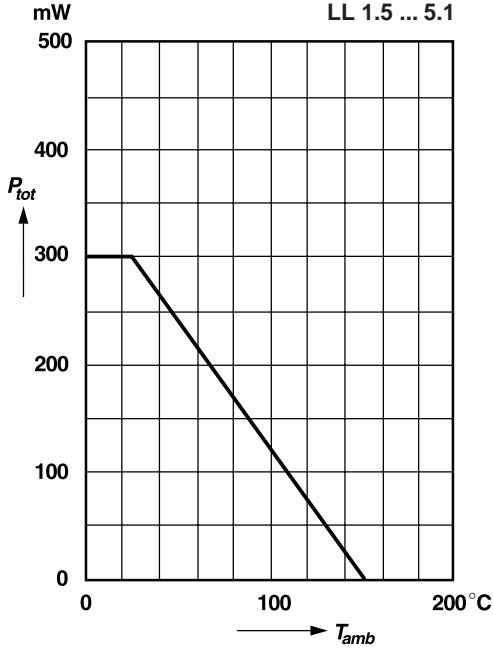


Vishay Semiconductors
formerly General Semiconductor

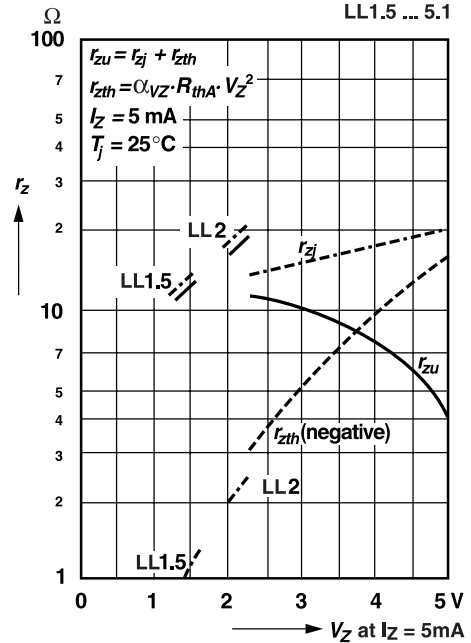
Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Admissible power dissipation versus ambient temperature

Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature



Dynamic resistance versus operating voltage



Dynamic resistance versus operating current, normalized

